

NL17SG07E

Buffer with Open Drain Output

The NL17SG07E MiniGate™ is an advanced high-speed CMOS Buffer with Open Drain Output in ultra-small footprint.

The NL17SG07E input and output structures provide protection when voltages up to 3.6 V are applied regardless of the supply voltage.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 2.5$ ns (Typ) at $V_{CC} = 3.0$ V, $C_L = 15$ pF
- Low Power Dissipation: $I_{CC} = 0.5$ μ A (Max) at $T_A = 25^\circ$ C
- 3.6 V Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

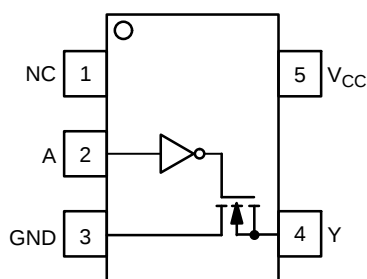


Figure 1. SC-88A
(Top View)

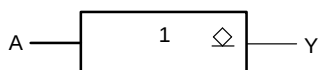


Figure 2. Logic Symbol



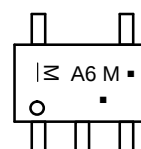
ON Semiconductor®

www.onsemi.com



**SC-88A
DF SUFFIX
CASE 419A**

MARKING DIAGRAM



M = Date Code*
■ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

PIN	NAME
1	NC
2	A
3	GND
4	Y
5	V_{CC}

FUNCTION TABLE

Input A	Output Y
L	L
H	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NL17SG07E

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	-0.5 to +4.6	V
V_{IN}	DC Input Voltage	-0.5 to +4.6	V
V_{OUT}	DC Output Voltage Active Mode, LOW State Tri-State Mode, Output at Hi-Z State Power-Down Mode ($V_{CC} = 0$ V)	-0.5 to $V_{CC} + 0.5$ -0.5 to +4.6 -0.5 to +4.6	V
I_{IK}	DC Input Diode Current $V_{IN} < GND$	-20	mA
I_{OK}	DC Output Diode Current $V_{OUT} < GND$	-20	mA
I_{OUT}	DC Output Source/Sink Current	± 20	mA
I_{CC}	DC Supply Current per Supply Pin	± 20	mA
I_{GND}	DC Ground Current per Ground Pin	± 20	mA
T_{STG}	Storage Temperature Range	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T_J	Junction Temperature Under Bias	+150	°C
MSL	Moisture Sensitivity	Level 1	
F_R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage Human Body Model (Note 2)	>2000	V
$I_{LATCHUP}$	Latch-up Performance above V_{CC} and below GND at 125°C (Note 3)	± 75	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V_{CC}	Positive DC Supply Voltage	0.9	3.6	V
V_{IN}	Digital Input Voltage	0.0	3.6	V
V_{OUT}	Output Voltage Output at Low State Tri-State Mode, Output at Hi-Z State Power-Down Mode ($V_{CC} = 0$ V)	0.0 0.0 0.0	V_{CC} 3.6 3.6	V
T_A	Operating Temperature Range	-55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-55°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		0.9	V _{CC}			V _{CC}		V
			1.1 to 1.3	0.70 x V _{CC}			0.70 x V _{CC}		
			1.4 to 1.6	0.65 x V _{CC}			0.65 x V _{CC}		
			1.65 to 1.95	0.65 x V _{CC}			0.65 x V _{CC}		
			2.3 to 2.7	1.7			1.7		
			3.0 to 3.6	2.0			2.0		
V _{IL}	Low-Level Input Voltage		0.9			GND		GND	V
			1.1 to 1.3			0.30 x V _{CC}		0.30 x V _{CC}	
			1.4 to 1.6			0.35 x V _{CC}		0.35 x V _{CC}	
			1.65 to 1.95			0.35 x V _{CC}		0.35 x V _{CC}	
			2.3 to 2.7			0.7		0.7	
			3.0 to 3.6			0.8		0.8	
V _{OL}	Low-Level Output Voltage	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	0.9		0.1		0.1	V
			I _{OL} = 0.3 mA	1.1 to 1.3		0.25 x V _{CC}		0.25 x V _{CC}	
			I _{OL} = 1.7 mA	1.4 to 1.6		0.25 x V _{CC}		0.25 x V _{CC}	
			I _{OL} = 3.0 mA	1.65 to 1.95		0.45		0.45	
			I _{OL} = 4.0 mA	2.3 to 2.7		0.4		0.4	
			I _{OL} = 8.0 mA	3.0 to 3.6		0.4		0.4	
I _{IN}	Input Leakage Current	V _{IN} = 0 to 3.6 V	0.9 to 3.6			±0.1		±1.0	μA
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	3.6			0.5		10	μA
I _{OZ}	Output Tri-State Leakage Current	V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 0 to 3.6 V	0.9 to 3.6			1.0		10	μA
I _{OFF}	Power Off Leakage Current	V _{IN} = 0 to 3.6 V V _{OUT} = 0 to 3.6 V	0			1.0		10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NL17SG07E

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	Test Condition	V_{CC} (V)	$T_A = 25^\circ\text{C}$			$T_A = -55^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	
t_{PZL}	Propagation Delay, Enable Time, A to Y	$C_L = 10$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	12	–	–	–	ns
			1.1 to 1.3	–	5.5	7.9	–	9.0	
			1.4 to 1.6	–	4.0	5.7	–	7.3	
			1.65 to 1.95	–	3.3	3.9	–	5.9	
			2.3 to 2.7	–	2.7	3.3	–	4.5	
			3.0 to 3.6	–	2.4	2.9	–	3.7	
		$C_L = 15$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	12.5	–	–	–	ns
			1.1 to 1.3	–	5.8	8.1	–	9.2	
			1.4 to 1.6	–	4.1	6.0	–	7.4	
			1.65 to 1.95	–	3.4	4.0	–	6.2	
			2.3 to 2.7	–	2.8	3.4	–	4.6	
			3.0 to 3.6	–	2.5	3.0	–	3.7	
		$C_L = 30$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	13.2	–	–	–	ns
			1.1 to 1.3	–	6.2	8.7	–	9.8	
			1.4 to 1.6	–	4.5	6.2	–	7.6	
			1.65 to 1.95	–	3.5	4.2	–	6.4	
			2.3 to 2.7	–	3.0	3.6	–	4.7	
			3.0 to 3.6	–	2.6	3.1	–	3.9	
t_{PLZ}	Propagation Delay, Disable Time, A to Y	$C_L = 10$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	8.0	–	–	–	ns
			1.1 to 1.3	–	6.5	10.9	–	11.5	
			1.4 to 1.6	–	5.2	8.9	–	9.5	
			1.65 to 1.95	–	4.9	8.8	–	9.4	
			2.3 to 2.7	–	3.8	8.4	–	9.3	
			3.0 to 3.6	–	3.5	8.1	–	8.5	
		$C_L = 15$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	11.1	–	–	–	ns
			1.1 to 1.3	–	9.0	13.4	–	14	
			1.4 to 1.6	–	7.9	11.4	–	12.0	
			1.65 to 1.95	–	7.6	11.3	–	11.9	
			2.3 to 2.7	–	6.3	10.9	–	11.8	
			3.0 to 3.6	–	6.0	10.6	–	11.0	
		$C_L = 30$ pF, $R_1 = R_L = 5$ k Ω	0.9	–	16.2	–	–	–	ns
			1.1 to 1.3	–	14	20.2	–	20	
			1.4 to 1.6	–	13	18.9	–	19.5	
			1.65 to 1.95	–	12.5	18.8	–	19.4	
			2.3 to 2.7	–	11.2	18.4	–	19.3	
			3.0 to 3.6	–	11	18.1	–	18.3	
C_{IN}	Input Capacitance		0 to 3.6	–	3	–	–	–	pF
C_{PD}	Power Dissipation Capacitance (Note 4)		0.9 to 3.6	–	4	–	–	–	pF

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$.

NL17SG07E

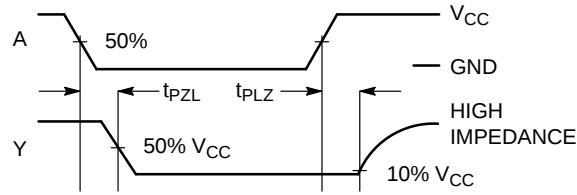
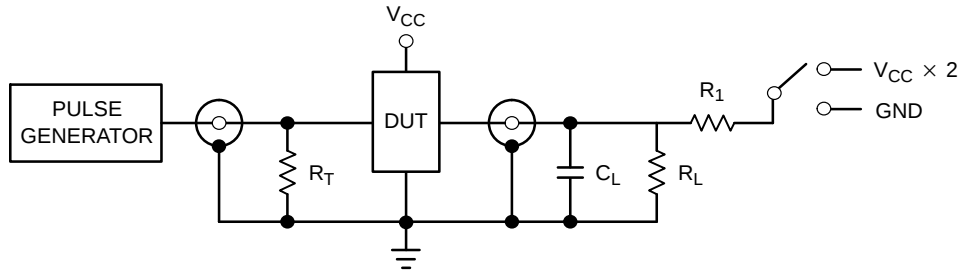


Figure 3. Switching Waveform



Test	Switch
t _{PZL}	V _{CC} × 2
t _{PLZ}	V _{CC} × 2

Figure 4. Test Circuit

ORDERING INFORMATION

Device	Package	Shipping [†]
NL17SG07EDFT2G	SC-88A (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

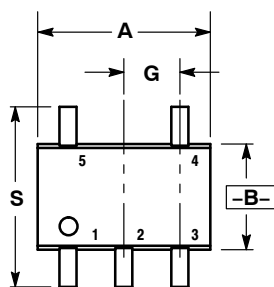
ON Semiconductor®



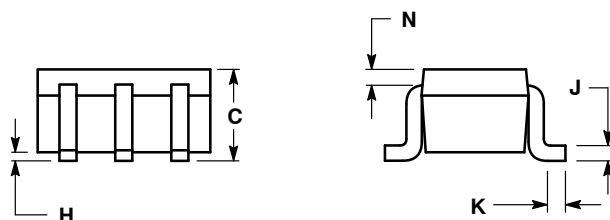
SCALE 2:1

SC-88A (SC-70-5/SOT-353)
CASE 419A-02
ISSUE L

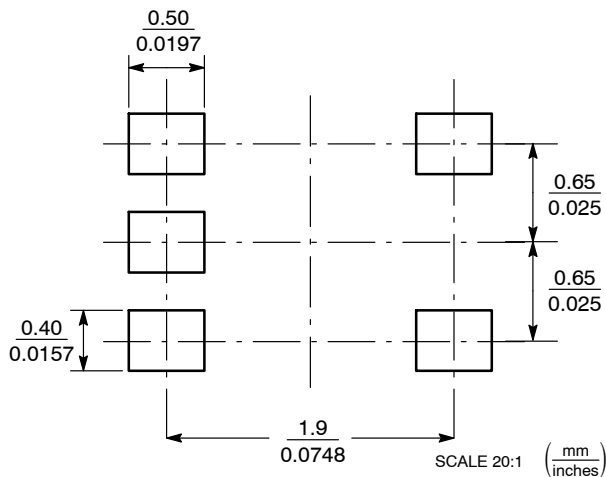
DATE 17 JAN 2013



D 5 PL $\oplus$ 0.2 (0.008) (M) B (M)



SOLDER FOOTPRINT

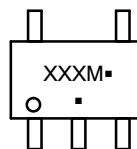


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

STYLE 6:
PIN 1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SC-88A (SC-70-5/SOT-353)	PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative